

CGD982HC

1 GHz, 22 dB gain GaAs high output power doubler Rev. 1 — 26 May 2014 Produc

Product data sheet

Product profile

1.1 General description

Hybrid amplifier module in a SOT115J package, operating at a supply voltage of 24 V Direct Current (DC), employing Hetero junction Field Effect Transistor (HFET) GaAs dies.

1.2 Features and benefits

- Excellent linearity
- Optimized for flat PAL D and flat NTSC loading
- Extremely low noise
- Excellent return loss properties
- Gain compensation over temperature
- Rugged construction
- Unconditionally stable
- Thermally optimized design
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

CATV systems operating in the 40 MHz to 862 MHz / 1003 MHz frequency range using PAL D or NTSC channel conditions.

1.4 Quick reference data

Quick reference data

Bandwidth 40 MHz to 1003 MHz; $V_B = 24 \ V$ (DC); $Z_S = Z_L = 75 \ \Omega$; $T_{mb} = 35 \ ^{\circ}$ C; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	f = 50 MHz	-	21.5	-	dB
		f = 1003 MHz	22	23	24	dB
СТВ	composite triple beat	$V_0 = 48 \text{ dBmV at } 862 \text{ MHz}$	-	-66	-62	dBc
CSO	composite second-order distortion	V _o = 48 dBmV at 862 MHz [1]	-	-69	-62	dBc
I _{tot}	total current	[2]	-	440	460	mA

^{[1] 98} PAL D channels with 8 MHz bandwidth per channel; [f = 47 MHz to 862 MHz]; flat V_0 till 862 MHz.



^[2] Direct Current (DC).

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2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	input		~ 1
2, 3	common	1 3 5 7 9	5 9
5	+V _B		>
7, 8	common		12 3 7 8
9	output		sym095

3. Ordering information

Table 3. Ordering information

Type number	Packag	Package				
	Name	Description	Version			
CGD982HC	-	rectangular single-ended package; aluminium flange; 2 vertical mounting holes; $2 \times 6-32$ UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads	SOT115J			

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{B}	supply voltage		-	30	V
$V_{i(RF)}$	RF input voltage	single tone	-	75	dBmV
T _{stg}	storage temperature		-40	+100	°C
T _{mb}	mounting base temperature		-20	+100	°C

5. Characteristics

Table 5. Characteristics

Bandwidth 40 MHz to 1003 MHz; $V_B = 24 \text{ V (DC)}$; $Z_S = Z_L = 75 \Omega$; $T_{mb} = 35 \text{ °C}$; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	f = 50 MHz	-	21.5	-	dB
		f = 870 MHz	-	22.5	-	dB
		f = 1003 MHz	22	23	24	dB
SL _{sl}	slope straight line	f = 40 MHz to 1003 MHz	0.5	-	2	dB
FL	flatness of frequency response	f = 40 MHz to 1003 MHz	-	-	1	dB

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Table 5. Characteristics ... continued

Bandwidth 40 MHz to 1003 MHz; $V_B = 24 \text{ V (DC)}$; $Z_S = Z_L = 75 \Omega$; $T_{mb} = 35 \text{ °C}$; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
RLin	input return loss	f = 40 MHz to 160 MHz	20	-	-	dB
		f = 160 MHz to 320 MHz	20	-	-	dB
		f = 320 MHz to 640 MHz	19	-	-	dB
		f = 640 MHz to 870 MHz	17	-	-	dB
		f = 870 MHz to 1003 MHz	16	-	-	dB
RL _{out} output return	output return loss	f = 40 MHz to 160 MHz	20	-	-	dB
		f = 160 MHz to 320 MHz	20	-	-	dB
		f = 320 MHz to 640 MHz	19	-	-	dB
		f = 640 MHz to 870 MHz	18	-	-	dB
		f = 870 MHz to 1003 MHz	17	-	-	dB
NF	noise figure	f = 50 MHz	-	4.6	5.6	dB
		f = 1003 MHz	-	5.5	6.5	dB
I _{tot}	total current	[3]	-	440	460	mA

- [1] G_p at 1003 MHz minus G_p at 40 MHz.
- [2] Flatness is defined as peak deviation to straight line.
- [3] Direct Current (DC).

Table 6. Distortion characteristics

Bandwidth 40 MHz to 1003 MHz; $V_B = 24 \ V \ (DC)$; $Z_S = Z_L = 75 \ \Omega$; $T_{mb} = 35 \ ^{\circ}C$; unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
98 PAL D	channels				'		
СТВ	composite triple beat	V _o = 48 dBmV at 862 MHz	[1]	-	-66	-62	dBc
		V _o = 50 dBmV at 862 MHz	[1]	-	-62	-	dBc
CSO	composite second-order distortion	V _o = 48 dBmV at 862 MHz	[1]	-	-69	-62	dBc
		V _o = 50 dBmV at 862 MHz	[1]	-	-65	-	dBc
Xmod	cross modulation	V _o = 48 dBmV at 862 MHz	[1]	-	-68	-	dB
		V _o = 50 dBmV at 862 MHz	[1]	-	-60	-	dB
112 NTS	C channels				'		
СТВ	composite triple beat	V _o = 48 dBmV at 750 MHz	[2]	-	-63	-	dBc
CSO	composite second-order distortion	V _o = 48 dBmV at 750 MHz	[2]	-	-66	-	dBc
Xmod	cross modulation	V _o = 48 dBmV at 750 MHz	[2]	-	-66	-	dB
79 NTSC	channels + 75 digital channels						
СТВ	composite triple beat	V _o = 56.4 dBmV at 1003 MHz	[3]	-	-75	-	dBc
CSO	composite second-order distortion	V _o = 56.4 dBmV at 1003 MHz	[3]	-	-77	-	dBc
Xmod	cross modulation	V _o = 56.4 dBmV at 1003 MHz	[3]	-	-68	-	dB
CCN	carrier-to-composite noise	V _o = 56.4 dBmV at 1003 MHz	[3]	-	57	-	dBc

^{[1] 98} PAL D channels with 8 MHz bandwidth per channel; [f = 47 MHz to 862 MHz]; flat V_o till 862 MHz.

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^{[2] 112} NTSC channels; [f = 45 MHz to 750 MHz]; flat V_0 till 750 MHz.

^{[3] 79} NTSC channels [f = 54 MHz to 550 MHz] + 75 digital channels [f = 550 MHz to 1003 MHz] (-6 dB offset); tilt extrapolated to 13.5 dB at 1003 MHz.

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6. Package outline

Rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads

SOT115J

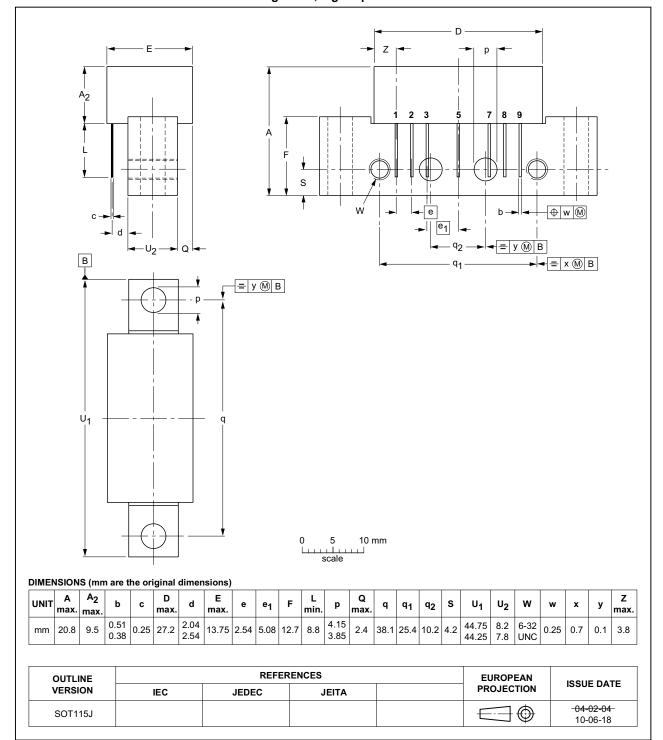


Fig 1. Package outline SOT115J

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7. Abbreviations

Table 7. Abbreviations

Acronym	Description
CATV	Community Antenna TeleVision
GaAs	Gallium-Arsenide
NTSC	National Television Standard Committee
PAL D	Phase Alternate Line standard D
UNC	UNified Coarse

8. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
CGD982HC v.1	20140526	Product data sheet	-	-

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9. Legal information

9.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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